

VOLTAGE RANGE: 40 - 200V

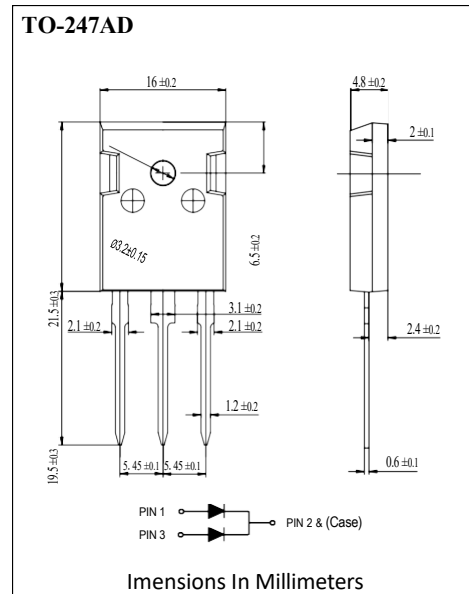
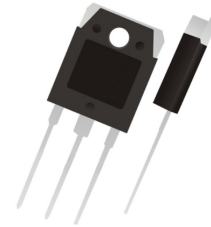
CURRENT: 40A

Features

- High efficiency operation and Low power loss
- Low stored charge majority carrier conduction
- High forward surge capability
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std..(Halogen Free)

Mechanical Data

- Circuit figure: Common Cathode
- Leads: Solderable per mil-std-202, Method 208
- Polarity: as marked
- Mounting torque: 5 in-lbs maximum
- Terminals: Puretin plated
- Weight: 5.85



Maximum Ratings and Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise specified

RATINGS	SYMBOL	MBR40H40PT	MBR40H45PT	MBR40H60PT	MBR40H100PT	MBR40H150PT	MBR40H200PT	UNIT	
Maximum repetitive reverse voltage	VRRM	40	45	60	100	150	200	V	
Maximum RMS voltage	VRMS	28	32	42	70	105	140	V	
Maximum DC blocking voltage	VDC	40	45	60	100	150	200	V	
Maximum average forward current per device per diode	IAV	40 20							A
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load	IFSM	380							A
Typical thermal resistance (Note 1)	R θ -JC	1.5							$^\circ\text{C}/\text{W}$
Operating junction temperature range	TJ	-55 to +150				-55 to +175		$^\circ\text{C}$	
Storage temperature range	TSTG	-55 to +175							$^\circ\text{C}$
Maximum forward voltage per leg at IF=20A	VF	0.65		0.75	0.85	0.95		V	
Maximum average reverse current at rated DC blocking voltage TJ=25 $^\circ\text{C}$ TJ=100 $^\circ\text{C}$	IR	0.10 30			0.02 10	0.01 5		mA	

Notes: 1. Thermal resistance from junction to case.



FIG. 1 - TYPICAL FORWARD CURRENT DERATING CURVE

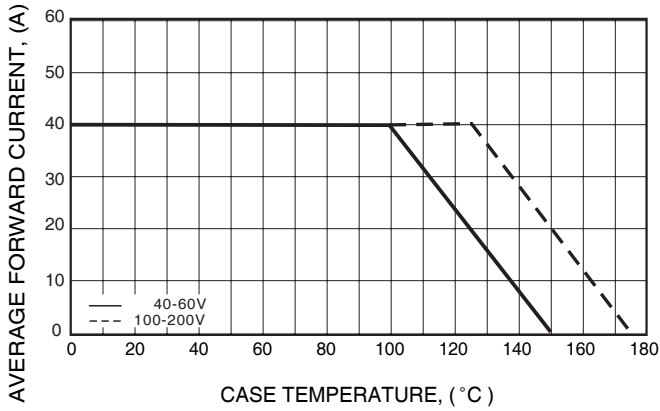


FIG. 2 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

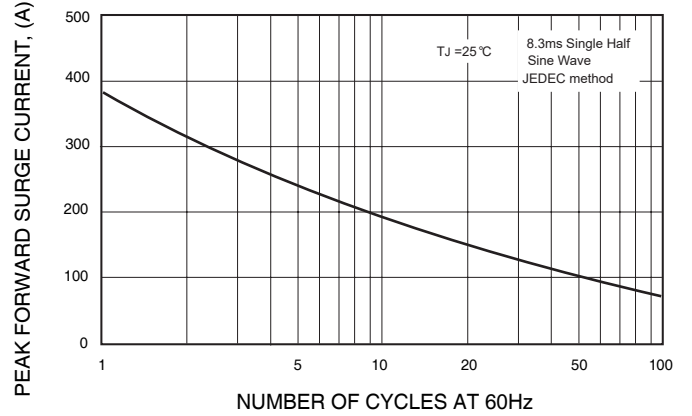


FIG. 3 - TYPICAL REVERSE CHARACTERISTICS

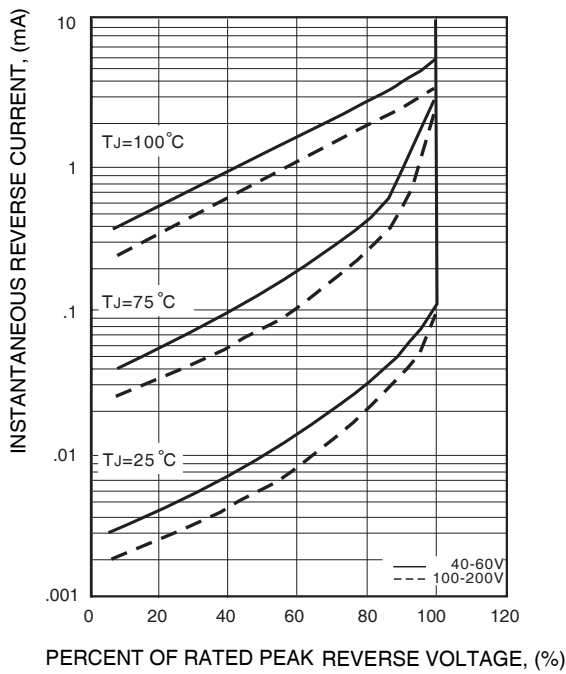


FIG. 4 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

